

## INCHANGE SEMICONDUCTOR

## **isc Silicon NPN Power Transistor**

# 2SC3280

### DESCRIPTION

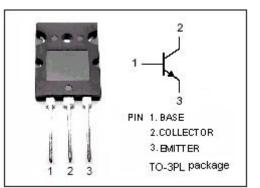
- Collector-Emitter Breakdown Voltage-: V<sub>(BR)CEO</sub>= 160V(Min)
- Collector-Emitter Saturation Voltage-: V<sub>CE(sat)</sub>= 2.0V(Max)@ I<sub>C</sub>= 8A
- Complement to Type 2SA1301
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

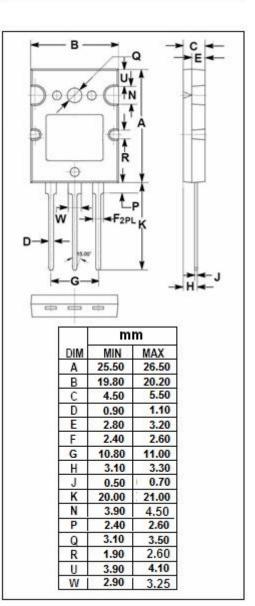
#### **APPLICATIONS**

- · Power amplifier applications
- Recommend for 80W high fidelity audio frequency amplifier output stage applications

### ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>CBO</sub>	Collector-Base Voltage	160	V
V <sub>CEO</sub>	Collector-Emitter Voltage	160	V
V <sub>EBO</sub>	Emitter-Base voltage	5	V
lc	Collector Current-Continuous	12	А
I <sub>B</sub>	Base Current-Continuous	1.2	А
Pc	Collector Power Dissipation @ T <sub>c</sub> =25°C	120	W
TJ	Junction Temperature	150	°C
Tstg	Storage Temperature Range	-55~150	°C







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# ELECTRICAL CHARACTERISTICS

Tc=25℃	unless	otherwise	specified
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SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 50mA; I <sub>B</sub> = 0	160			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 8A; I <sub>B</sub> = 0.8A			2.0	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = 6A; V <sub>CE</sub> = 5V			1.5	V
Ісво	Collector Cutoff Current	V <sub>CB</sub> = 160V; I <sub>E</sub> = 0			5.0	μA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 5V; I <sub>C</sub> = 0			5.0	μA
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 1A; V <sub>CE</sub> = 5V	55		160	
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 6A; V <sub>CE</sub> = 5V	35			
fT	Current-Gain—Bandwidth Product	I <sub>C</sub> = 1A; V <sub>CE</sub> = 5V		30		MHz
Сов	Output Capacitance	I <sub>E</sub> = 0; V <sub>CB</sub> = 10V, f <sub>test</sub> = 1MHz		220		pF

#### h<sub>FE-1</sub> Classifications

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55-110	80-160	

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